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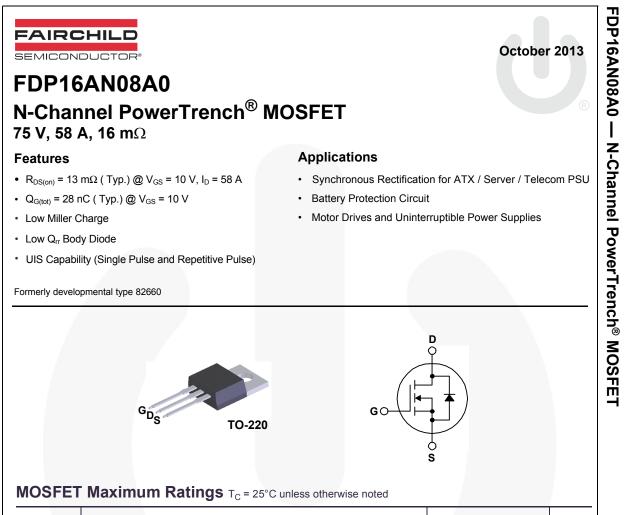


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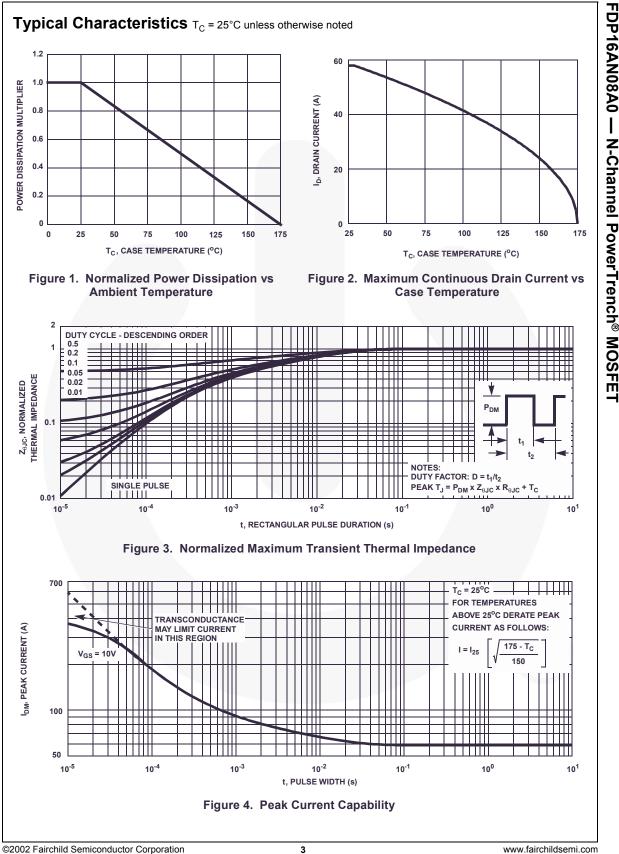
Symbol	Parameter	FDP16AN08A0	Unit V	
V <sub>DSS</sub>	Drain to Source Voltage	75		
V <sub>GS</sub>	Gate to Source Voltage	±20	V	
I <sub>D</sub>	Drain Current			
	Continuous ( $T_C = 25^{\circ}C$ , $V_{GS} = 10V$ )	58	А	
	Continuous ( $T_C = 100^{\circ}C$ , $V_{GS} = 10V$ )	44		
	Continuous ( $T_{amb}$ = 25°C, $V_{GS}$ = 10V, with $R_{\theta JA}$ = 43°C/W)	9	А	
	Pulsed	Figure 4	A	
E <sub>AS</sub>	Single Pulse Avalanche Energy (Note 1)	117	mJ	
P <sub>D</sub>	Power dissipation	135	W	
	Derate above 25°C	0.9	W/ºC	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature	-55 to 175	°C	

#### **Thermal Characteristics**

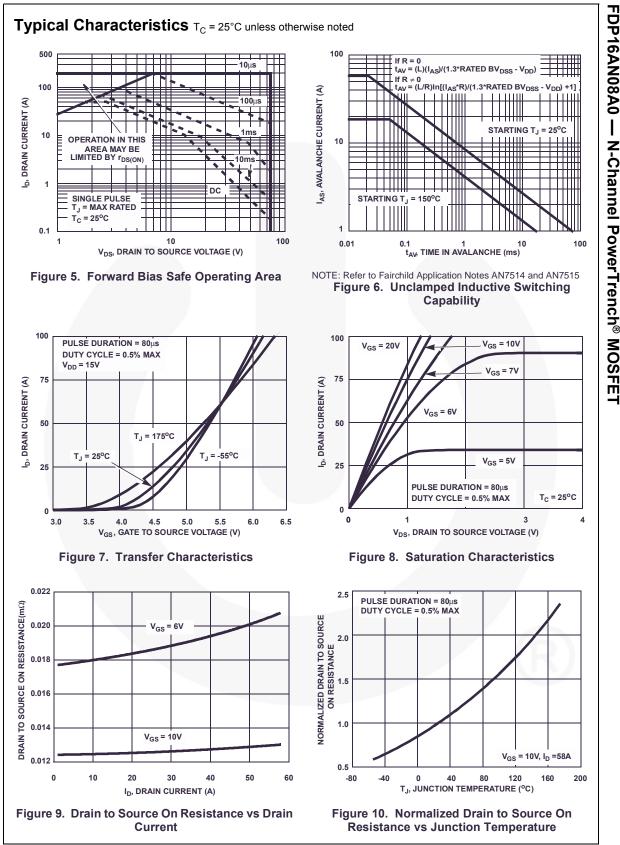
$R_{ ext{ heta}JC}$	Thermal Resistance Junction to Case, Max.	1.11	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance Junction to Ambient (Note 2), Max.	62	°C/W

Device	Marking	Device	Package	Reel Size	Tape V	Vidth	Quar	ntity	
FDP16AN08A0		FDP16AN08A0	TO-220	Tube	N/.			) units	
Electric		octorictico - com							
Symbol		<b>Acteristics</b> T <sub>C</sub> = 25°C Parameter		onditions	Min	Тур	Max	Unit	
Off Char	acteristic	c			•		+		
_				- 0) (	75	1		V	
B <sub>VDSS</sub>	Drain to S	Source Breakdown Voltage	$I_{\rm D} = 250 \mu A, V_{\rm DS}$	<sub>GS</sub> = 0V	75	-	- 1	V	
I <sub>DSS</sub> Zero Gate		te Voltage Drain Current	$V_{\rm DS} = 00V$ $V_{\rm GS} = 0V$ $V_{\rm GS} = \pm 20V$	T <sub>C</sub> = 150°C	-	-	250	μΑ	
I <sub>GSS</sub>	Gate to Source Leakage Current			1 <sup>°</sup> C = 130 <sup>°</sup> C	-	-	±100		
			65		1	1			
	acteristic								
V <sub>GS(TH)</sub>	Gate to S	ource Threshold Voltage	$V_{GS} = V_{DS}, I_{D}$		2	-	4	V	
			$I_D = 58A, V_{GS}$		-	0.013	0.016		
r <sub>DS(ON)</sub>	Drain to S	ource On Resistance	$I_{\rm D} = 29$ A, $V_{\rm GS}$	= 6V	-	0.019	0.029	Ω	
			I <sub>D</sub> = 58A, V <sub>GS</sub> T <sub>J</sub> = 175°C	= 100,	-	0.032	0.037		
Dynamic	Characte	eristics							
C <sub>ISS</sub>	Input Cap	acitance		0) (	-	1857	-	pF	
C <sub>OSS</sub>	Output Ca	apacitance		$_{\rm SS} = 0V$ ,	-	288	-	pF	
C <sub>RSS</sub>	Reverse 1	Fransfer Capacitance	1 110112		-	88	-	pF	
Q <sub>g(TOT)</sub>	Total Gate	e Charge at 10V	$V_{GS}$ = 0V to 1			28	42	nC	
Q <sub>g(TH)</sub>	Threshold	I Gate Charge	$V_{GS}$ = 0V to 2	V V <sub>DD</sub> = 40V	-	3.5	5	nC	
Q <sub>gs</sub>	Gate to S	ource Gate Charge		I <sub>D</sub> = 58A	-	11	-	nC	
Q <sub>gs2</sub>		rge Threshold to Plateau		I <sub>g</sub> = 1.0mA	-	7.6	-	nC	
Q <sub>gd</sub>	Gate to D	rain "Miller" Charge			-	6.4	-	nC	
Switchin	g Charac	teristics (V <sub>GS</sub> = 10V)							
t <sub>ON</sub>	Turn-On T	Time			-	-	135	ns	
t <sub>d(ON)</sub>	Turn-On E	Delay Time				8	- /	ns	
t <sub>r</sub>	Rise Time	9	V <sub>DD</sub> = 40V, I <sub>D</sub>		-	82	-	ns	
t <sub>d(OFF)</sub>	Turn-Off E	Delay Time	V <sub>GS</sub> = 10V, R	$V_{GS} = 10V, R_{GS} = 10\Omega$		28	-	ns	
t <sub>f</sub>	Fall Time					30	- 1	ns	
t <sub>OFF</sub>	Turn-Off T	Time			-	- /	86	ns	
Drain-So	urce Diod	de Characteristics							
Vaa	Source to	Drain Diode Voltage	I <sub>SD</sub> = 58A		-	-	1.25	V	
V <sub>SD</sub>			I <sub>SD</sub> = 29A		-	-	1.0	V	
t <sub>rr</sub>		Recovery Time		<sub>D</sub> /dt = 100A/µs	-	-	35	ns	
Q <sub>RR</sub>	Reverse F	Recovered Charge	I <sub>SD</sub> = 58A, dI <sub>S</sub>	I <sub>SD</sub> = 58A, dI <sub>SD</sub> /dt = 100A/μs		-	36	nC	

FDP16AN08A0 — N-Channel PowerTrench® MOSFET

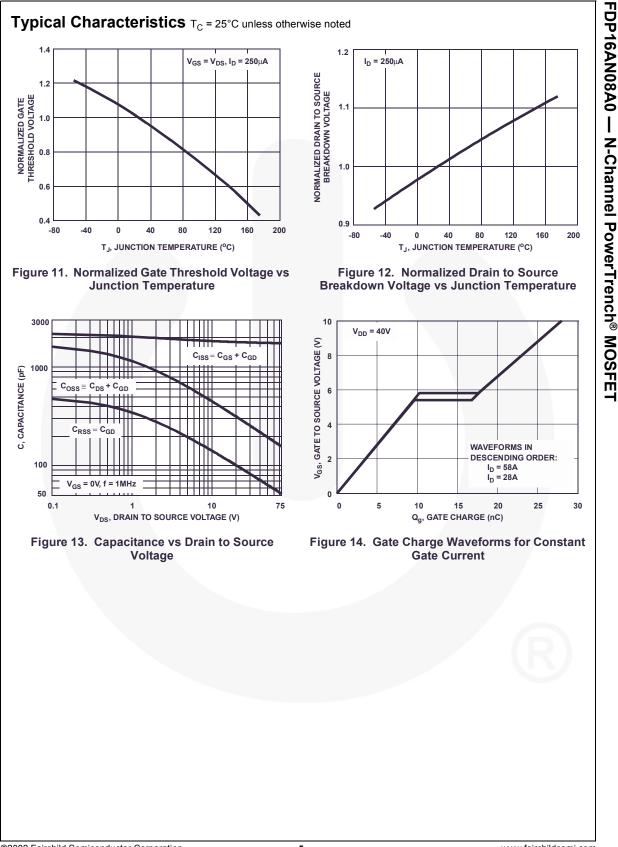


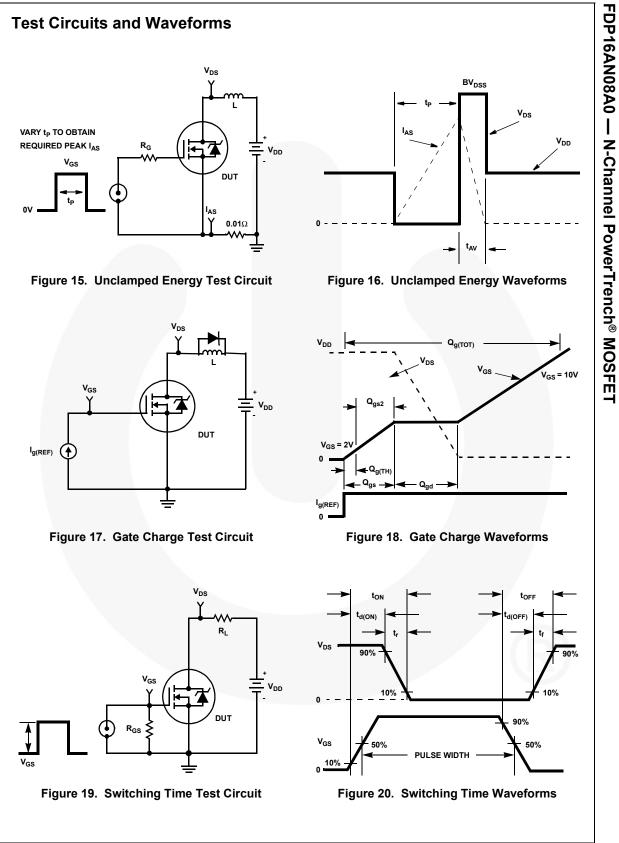
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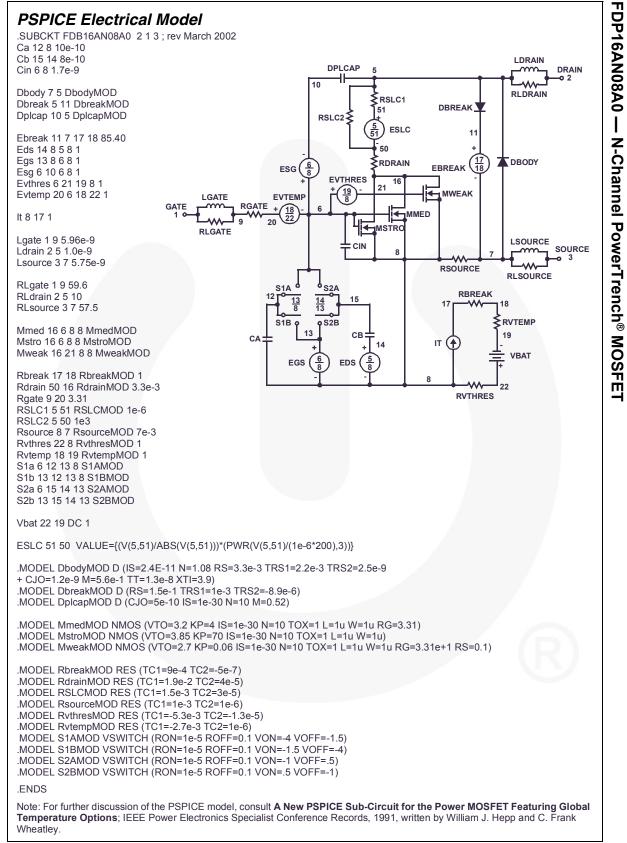
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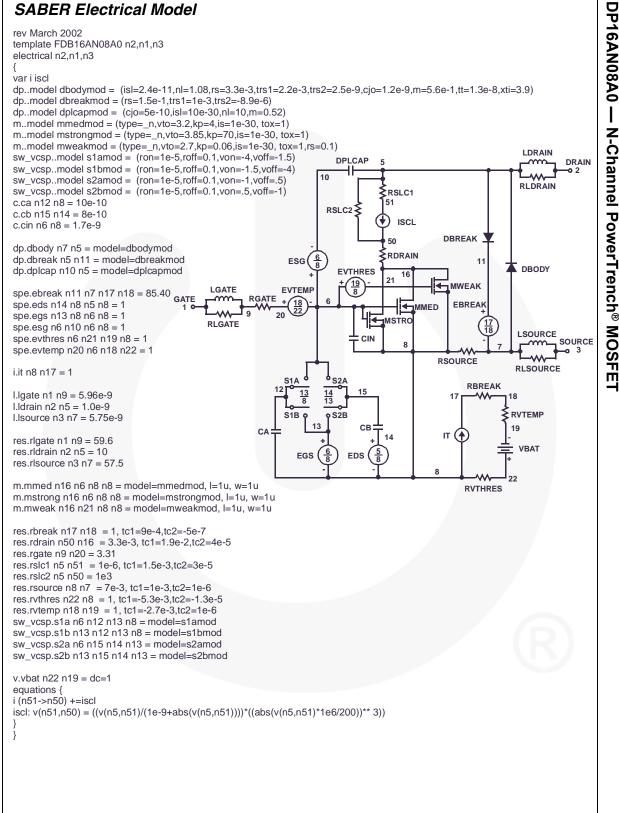
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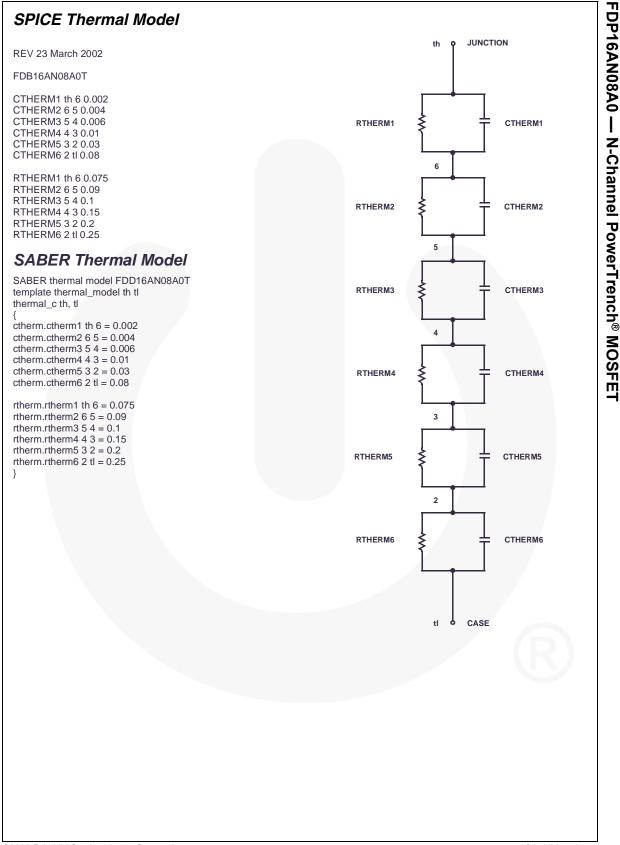
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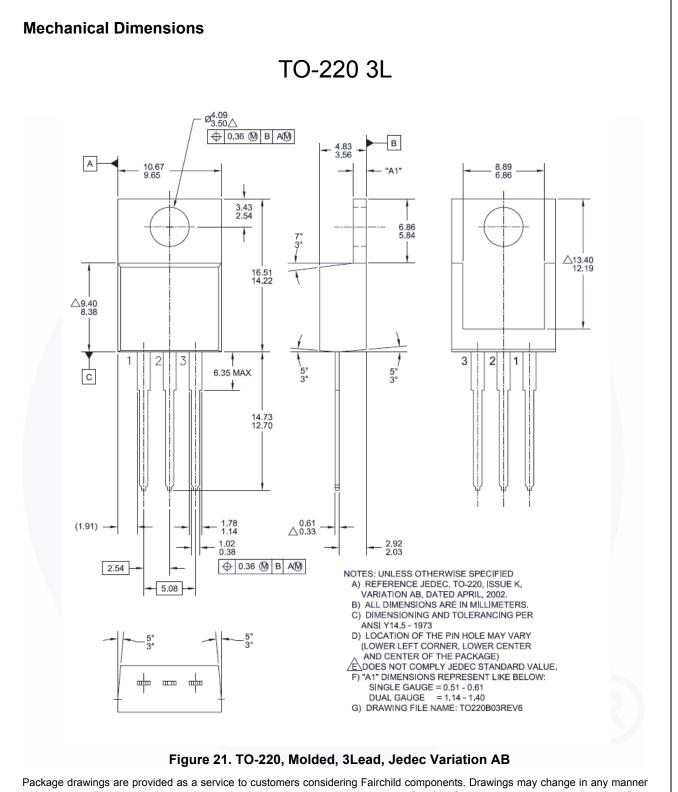
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### SABER Electrical Model



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Dimension in Millimeters



Not In Production

Obsolete

Datasheet contains specifications on a product that is discontinued by Fairchild

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